



自主封測 品質把控 售後保障

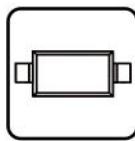
WEB | [WWW.TDSEMIC.COM](http://WWW.TDSEMIC.COM)



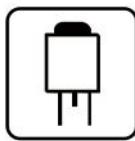
電源管理



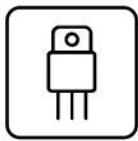
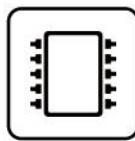
顯示驅動



二三極管 LDO穩壓器



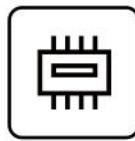
觸摸芯片



MOS管



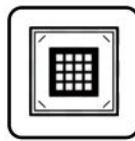
運算放大器



存儲芯片



MCU

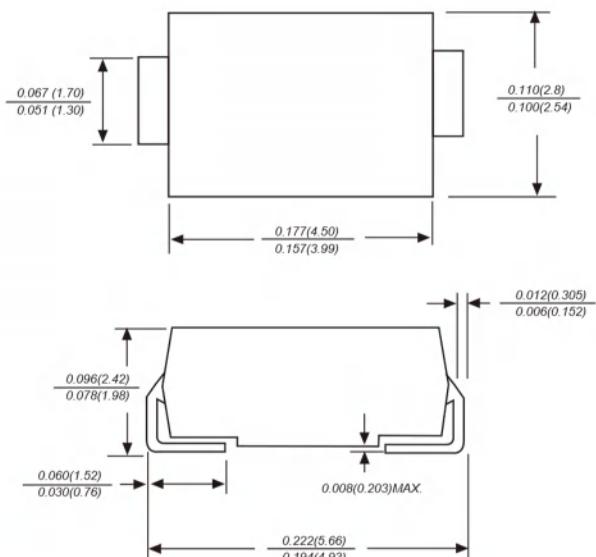


串口通信

SS24

產品規格說明書

### SMA/DO-214AC



Dimensions in inches and (millimeters)

### FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Metal silicon junction,majority carrier conduction
- ◆ Low power loss,high efficiency
- ◆ Built-in strain relief,ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed: 260°C/10 seconds at terminals

### MECHANICAL DATA

**Case:** JEDEC DO-214AC molded plastic body

**Terminals:** leads solderable per MIL-STD-750, Method 2026

**Polarity:** Color band denotes cathode end

**Mounting Position:** Any

**Weight:** 0.002 ounce, 0.07 grams

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

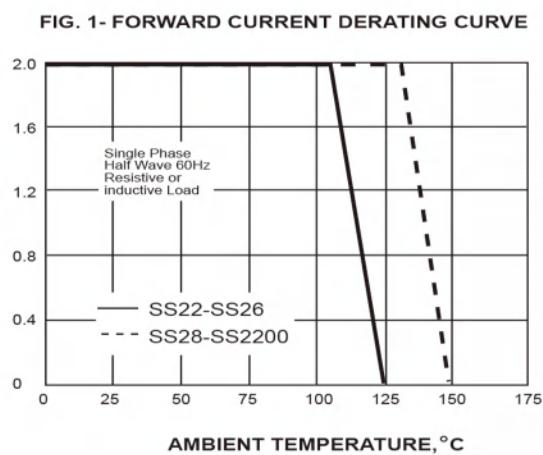
Single phase half-wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%.

	SYMBOLS	SS22	SS23	SS24	SS25	SS26	SS28	SS210	SS2150	SS2200	UNITS		
Maximum repetitive peak reverse voltage	$V_{RRM}$	20	30	40	50	60	80	100	150	200	VOLTS		
Maximum RMS voltage	$V_{RMS}$	14	21	28	35	42	56	70	105	140	VOLTS		
Maximum DC blocking voltage	$V_{DC}$	20	30	40	50	60	80	100	150	200	VOLTS		
Maximum average forward rectified current at $T_L$ (see fig.1)	$I_{(AV)}$	2.0								Amps			
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	50.0								Amps			
Maximum instantaneous forward voltage at 2.0A	$V_F$	0.55		0.70		0.85		0.95	Volts				
Maximum DC reverse current $T_A=25^\circ C$ at rated DC blocking voltage $T_A=100^\circ C$	$I_R$	0.5				0.2				mA			
		10.0				5.0							
Typical junction capacitance (NOTE 1)	$C_J$	220		180									
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	75.0								$^\circ C/W$			
Operating junction temperature range	$T_J$	-65 to +125				-65 to +150				$^\circ C$			
Storage temperature range	$T_{STG}$	-65 to +150								$^\circ C$			

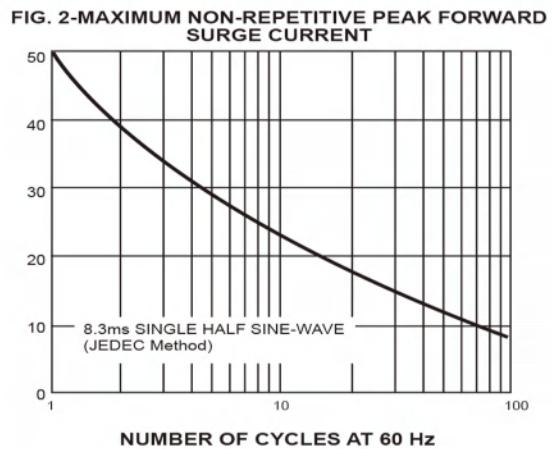
**Note:**1.Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2.P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

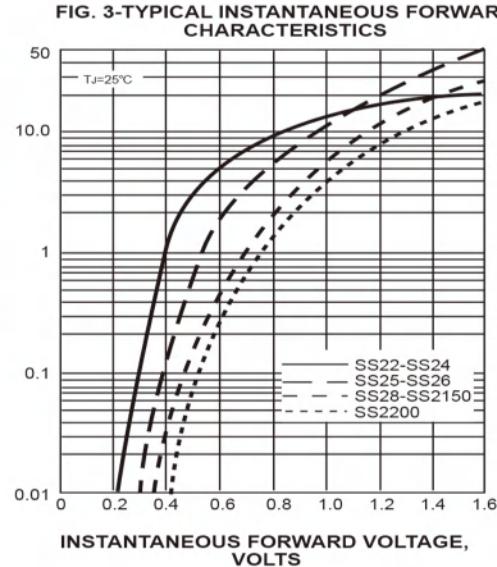
AVERAGE FORWARD RECTIFIED CURRENT, AMPERES



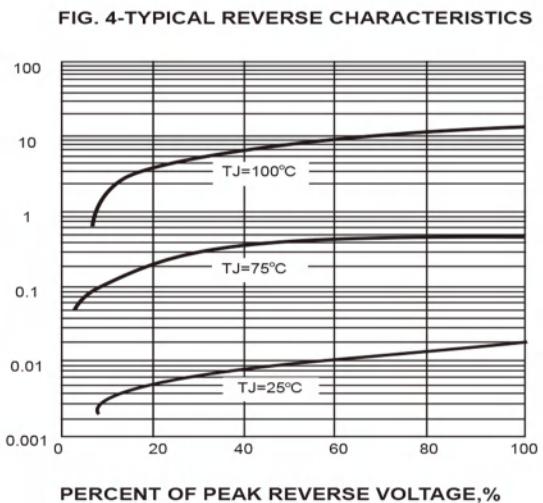
PEAK FORWARD SURGE CURRENT, AMPERES



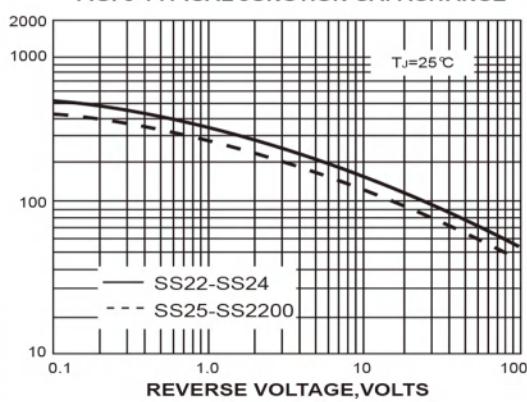
INSTANTANEOUS FORWARD CURRENT, AMPERES



INSTANTANEOUS REVERSE CURRENT, MILLIAMPERES



JUNCTION CAPACITANCE, pF



TRANSIENT THERMAL IMPEDANCE, °C/W

